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Evolution of Magnetic and Electronic Properties of Spinel Cr_xFe_{3-x}O₄ Thin Films

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In this study, by substituting Cr in Fe_1O_4 , $Cr_xFe_{1x}O_4$ thin film samples were prepared by sol-gel method on Si(100) substrates. The samples were found to be polycrystalline in nature and the Cr-doped ones maintained the same structure as that of Fe_3O_4 up to x=0.95 without any secondary phases. The lattice constant is decreased slightly with increasing Cr composition with the value for x=0.95 reduced by 0.05% compared to that of Fe_3O_4 . The decrease of lattice constant can be explained in terms of substitution of octahedral Fe^{3s} sites by Cr^{3s} ions. The $Cr_xFe_{3x}O_4$ films were found to exhibit n-type character with resistivity increasing with increasing Cr content.

Magnetic hysteresis curves of the samples measured at room temperature indicate that the saturation magnetization (M_s) increases at low Cr composition (x \leq 0.05) and decrease as x increases further. On the other hand, the coercivity (H_s) increases as x increases. Simple comparison of the spin magnetic moment of Cr¹ and Fe³⁺ insc an not explain the increase of M_s. The increase of M_s is attributable to the unquenched orbital angular momentum of octahedral Fe³⁺ ion [1] due to perturbation of octahedral Cr¹⁺ ions existing nearby. The increase of H_c is attributed to the increase of magnetic anisotropy by the existence of octahedral Cr¹⁺ iod³ ions. Magnetoresistance of Cr_xFe_{3x}O₄ films is found to decrease with increasing x as shown in Fig. 1 and the probable reason for it is discussed.

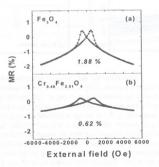


Fig. 1. Magnetoresistance measured for (a) Fe₃O₄ and (b) Cr_{0.49}Fe_{2.51}O₄ thin films at room temperature.

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